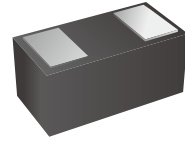


Ultra Low Capacitance ESD Protection Diode

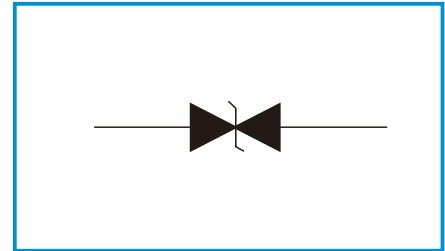
Features

- Transient protection for high-speed data lines
IEC 61000-4-2 (ESD) ±15kV (Air)
±8kV (Contact)
- IEC 61000-4-4 (EFT) 40A (5/50 ns)
Cable Discharge Event (CDE)
- Package optimized for high-speed lines
- Ultra-small package (1.0mm×0.6mm×0.5mm)
- Protects one data, control line
- Low capacitance: 0.25pF (Typical)
- Low leakage current
- Low clamping voltage



DFN1006

Functional Diagram



Mechanical Data

- DFN1006 package
- Flammability Rating: UL 94V-0
- High temperature soldering guaranteed: 260°C/10s
- Packaging: Tape and Reel
- Reel size: 7 inch
- Marking: 3BU

Applications

- Serial ATA
- Desktops, Servers and Notebooks
- Cellular Phones
- MDDI Ports
- USB Data Line Protection
- Display Ports
- Digital Visual Interfaces (DVI)

Absolute Maximum Ratings (T_{amb}=25°C unless otherwise specified)

| Symbol | Parameter | Value | Units |
|------------------|--|------------|-------|
| V _{ESD} | ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact) | ±20 ±20 | kV |
| P _{PP} | Peak Pulse Power (8/20μs) | 100 | W |
| T _{OPT} | Operating Temperature | -55~125 | °C |
| T _{STG} | Storage Temperature | -55~150 | °C |

Electrical Characteristics(TA=25°C unless otherwise specified)

| Symbol | Parameter | Test Condition | Min | Typ | Max | Units |
|-----------|---------------------------|---|-----|------|------|-------|
| V_{RWM} | Reverse Working Voltage | | | | 3.3 | V |
| V_{BR} | Reverse Breakdown Voltage | $I_T = 1\text{mA}$ | 4.2 | | | V |
| I_R | Reverse Leakage Current | $V_{RWM} = 3.3\text{V}$ | | | 100 | nA |
| V_C | Clamping Voltage | $I_{PP} = 1\text{A}, t_p = 8/20\mu\text{s}$ | | | 12 | V |
| | | $I_{PP} = 4\text{A}, t_p = 8/20\mu\text{s}$ | | | 25 | V |
| C_J | Junction Capacitance | $V_R = 0\text{V}, f = 1\text{MHz}$ | | 0.25 | 0.40 | pF |

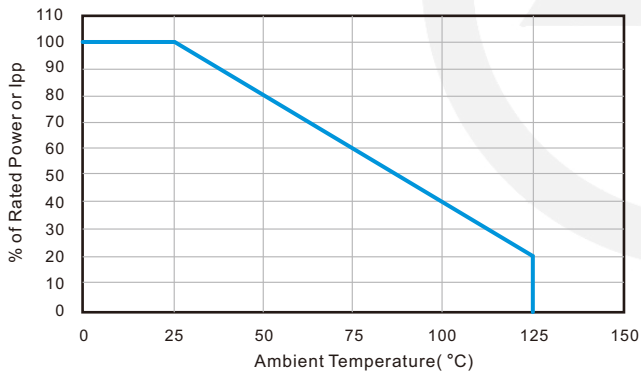
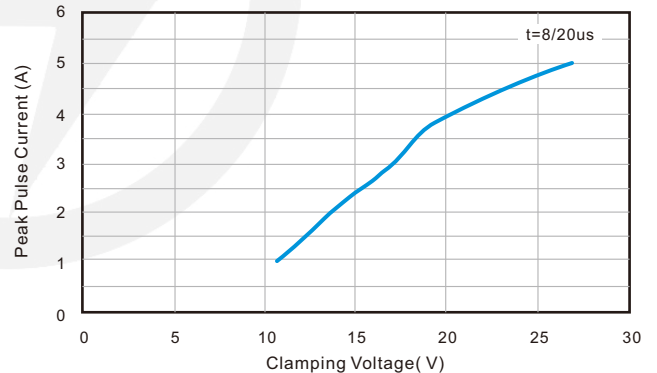
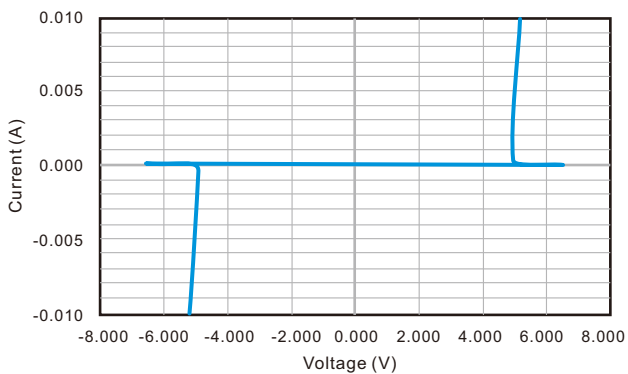
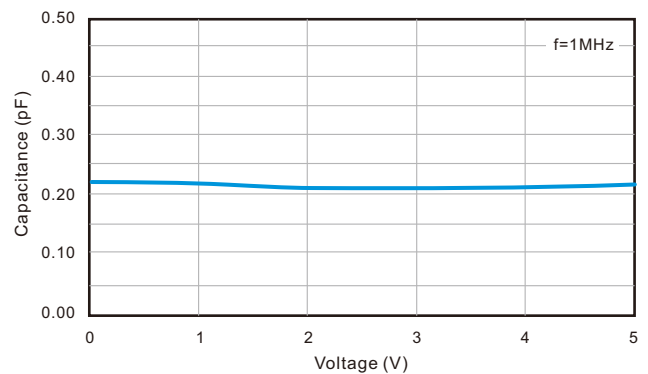
Characteristic Curves
Fig 1 Power Derating Curve

Fig 2 Clamping Voltage vs Peak Pulse Current

Fig 3 Voltage Sweeping

Fig 4 Voltage vs Capacitance


Fig 5 ESD Clamping
 (+8kV Contact per IEC 61000-4-2)

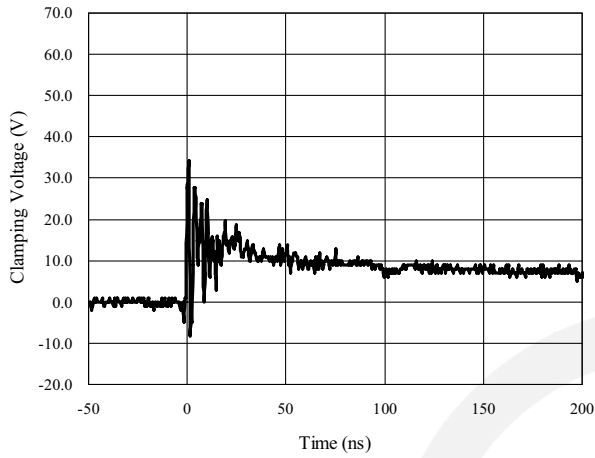
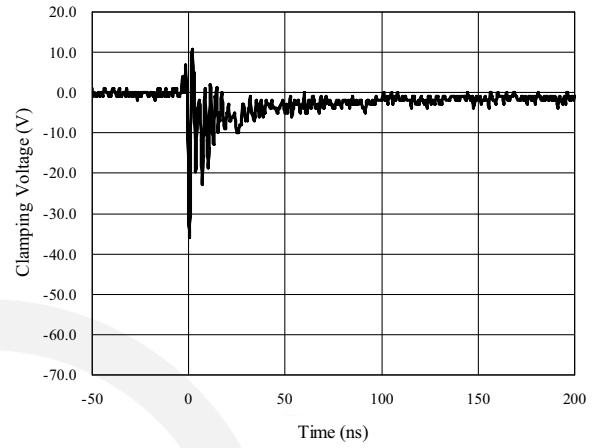
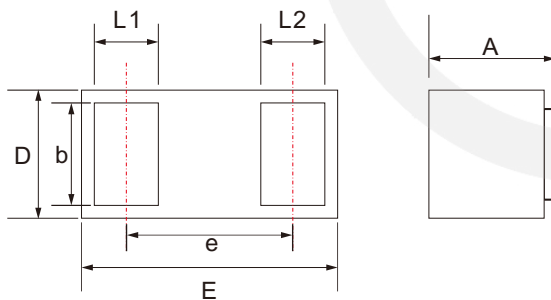


Fig 6 ESD Clamping
 (-8kV Contact per IEC 61000-4-2)



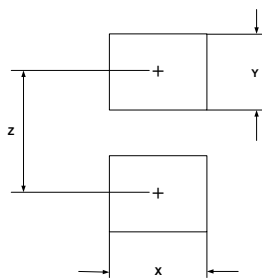
DFN1006 Package Outline

Unit: mm



| SYMBOL | DIMENSIONS | |
|--------|------------|-------|
| | MIN. | MAX. |
| D | 0.550 | 0.650 |
| E | 0.950 | 1.050 |
| L1 | 0.200 | 0.300 |
| L2 | 0.200 | 0.300 |
| b | 0.450 | 0.550 |
| e | 0.650 TYP. | |
| A | 0.450 | 0.550 |

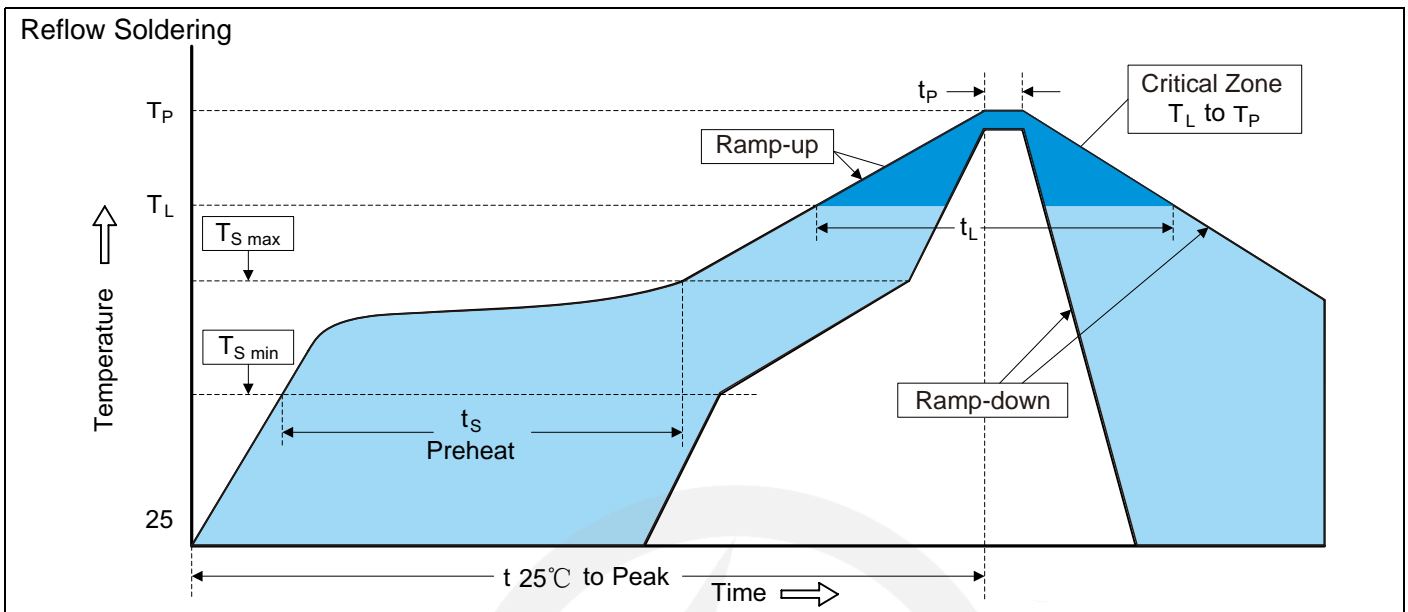
DFN1006 Suggested Pad Layout



| SYM | DIMENSIONS |
|-----|-------------|
| | MILLIMETERS |
| X | 0.50 |
| Y | 0.50 |
| Z | 0.90 |

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purpose only.

Recommended Soldering Conditions

Recommended Conditions

| Profile Feature | Pb-Free Assembly |
|---|----------------------------------|
| Average ramp-up rate (T_L to T_P) | 3°C/second max. |
| Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s) | 150°C 200°C 60-180 seconds |
| $T_{S\ max}$ to T_L -Ramp-up Rate | 3°C/second max. |
| Time maintained above: -Temperature (T_L) -Time (t_L) | 217°C 60-150 seconds |
| Peak Temperature (T_P) | 260°C |
| Time within 5°C of actual Peak Temperature (t_p) | 20-40 seconds |
| Ramp-down Rate | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |

7" Reel


| | |
|----|----------------------|
| D2 | $\Phi 178.0 \pm 2.0$ |
|----|----------------------|

| | |
|----|--------------------------|
| D3 | $\Phi 50.0 \text{ Min.}$ |
|----|--------------------------|

| | |
|----|---------------------|
| D4 | $\Phi 13.0 \pm 0.5$ |
|----|---------------------|

| | |
|----|----------------|
| W1 | 16.0 ± 2.0 |
|----|----------------|

Quantity: 10000PCS